

Company profile



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Shaoxing Ziyuan Polishing Co., Ltd.

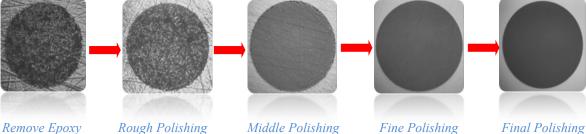
Shaoxing Ziyuan Polishing Co., Ltd. was established in 2012 to develop abrasive industry in China. We are committed to research and manufacture of paper abr products, lapping film, structural abrasive products, foamdisc, microfinishing fil polishing slurry and compounds. We have a professional research team with ric experience and we keep strong investment in developing new products and qu systems for metal working, AOEM, AAM, wood working, glass, ceramic and nonfe metal, etc. We have applied 16 patents and have our core advantages in technology advanced production line, timely service and professional all-in-one solutions. products are widely applied in fiber optical, micro motor, LCD, roller, automobil 3C industry and the customers are worldwide including USA, United Kingdom, Italy, India, Israel, Brazil, Argentina, Russia etc. We have the goal to supply the h products to the global market and sincerely welcome customers worldwide to us. We can provide OEM, ODM and One- stop service for you. We are young, You yuan fang lai, Bu yi Le hu(有朋自远方来,不亦乐乎),it is a delight thing when come together from afar. We are willing to share our value of trust, cooperation, and teamwork, we are chasing a win-win situation with our guest, and we are d to have a bright future.

More >



No.1 Seiko Giken SFP-550:

	C4		Polishing I	Film		Pr	ocess				
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Time			
1	Remove Epoxy	15/30	SiC/D	SC15/SC30/ D30	By hand	70 D	Dry	30-45s			
	•	Cleaning									
2	Rough Polishing	9	Diamond	D9	Clamps	80 D	DI water	20-40s			
Cleaning											
3	Middle Polishing	3	Diamond	D3	Clamps	80 D	DI water	20-40s			
	Cleaning										
4	Fine Polishing	1	Diamond	D1	Clamps	80 D	DI water	20-40s			
				Cleaning							
5	Final Polishing	0.01	SiO2	ADS	Clamps	70 D	DI water/ SOQ-12D	20-30s			
				Cleaning							



Note:

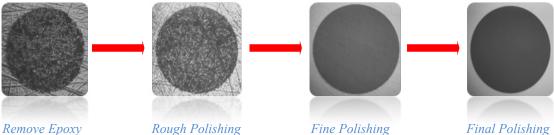
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





Seiko Giken SFP-550

•			- 41 4 1 -							
	Step		Polishing I	film		Pro	cess			
	э іер	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Time		
1	Remove Epoxy	15/30	SiC/D	SC15/SC30/ D30	By hand	70 D	Dry	30-45s		
	Cleaning									
2	Rough Polishing	9	Diamond	D9	Clamps	70/80 D	DI water	40-50s		
	Cleaning									
3	Fine Polishing	1	Diamond	D1	Clamps	80 D	DI water	40-50s		
	Cleaning									
4	Final Polishing	0.01 SiO2		ADS	Clamps	70 D	DI water/ SOQ-12D	20-30s		
				Cleaning						



Note:

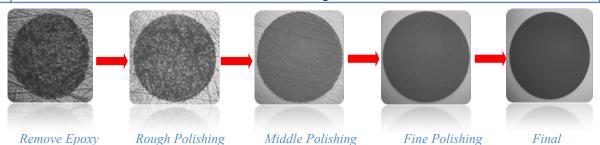
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





Seiko Instrument OFL-12(12UPC):

	C4 - · ·		Polishing F	ilm			Process				
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time		
1	Remove Epoxy	15/30	SiC/D	SC15/SC30 /D30	By hand	60 D	Dry	n/a	30-50s		
		Cleaning									
2	Rough Polishing	9	Diamond	D9	Point 1	60 D	DI water	140-220rpm	30-50s		
	Cleaning										
3	Middle Polishing	3	Diamond	D3	Point1	60 D	DI water	160-220rpm	30-50s		
		Cleaning									
4	Fine Polishing	1	Diamond	D1	Point 1	60 D	DI water	160-220rpm	30-50s		
Cleaning											
5	Final Polishing	0.01	SiO2	ADS	Point0.5-1	55 D	DI water/ SOQ-12D	160-220rpm	30-40s		
				Cle	eaning						



Polishing

Note:

In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.

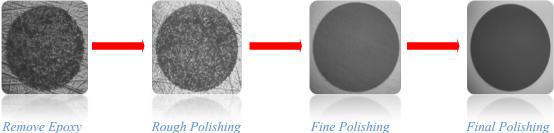
The gear in the pressure is mainly aimed at grinding machines similar to OFL-12. The weight used is about 475g. The first gear is the second scale of the lever, that is, after the long scale. This process is for reference only. The customer process also needs to be fine-tuned on site according to the different equipment, operation and 3D data of each customer.





Seiko Instrument OFL-12(12UPC):

			Polishing F	ilm			Process		
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time
1	Remove Epoxy	15/30	SiC/D	SC15/SC30 /D30	By hand	60 D	Dry	n/a	30-60s
	Cleaning								
2	Rough Polishing	9	Diamond	D9	Point 2	60 D	DI water	140-220rpm	40-60s
				Cle	eaning				
3	Fine Polishing	1	Diamond	D1	Point 2	60 D	DI water	160-220rpm	40-60s
Cleaning									
4	Final Polishing	0.01	SiO2	ADS	Point 1	55 D	DI water/ SOQ-12D	160-220rpm	30-40s
				Cle	eaning				



Note:

In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.

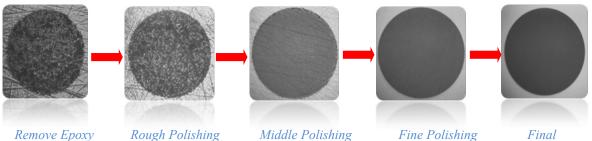
The gear in the pressure is mainly aimed at grinding machines similar to OFL-12. The weight used is about 475g. The first gear is the second scale of the lever, that is, after the long scale. This process is for reference only. The customer process also needs to be fine-tuned on site according to the different equipment, operation and 3D data of each customer.





Domaille 18UPC:

	Ct.		Polishing Fi	lm			Process				
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time		
1	Remove Epoxy	15/30	SiC/D	SC15/SC30 /D30	By hand	70 D	Dry	n/a	30-60s		
	Cleaning										
2	Rough Polishing	9	Diamond	D9	120g/pc	80 D	DI water	160-220rpm	30-50s		
	Cleaning										
3	Middle Polishing	3	Diamond	D3	150g/pc	80 D	DI water	160-220rpm	30-50s		
					Cleaning						
4	Fine Polishing	1	Diamond	D1	150g/pc	80 D	DI water	160-220rpm	30-50s		
Cleaning											
5	Final Polishing	0.01	SiO2	ADS	150g/pc	70 D	DI water/ SOQ-12D	160-220rpm	30-50s		
	Cleaning										



Polishing

Note:

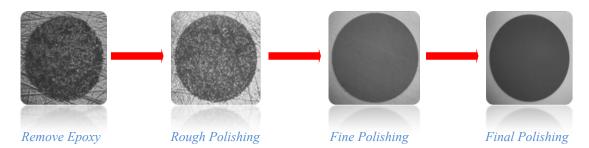
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





Domaille 18UPC:

	Cton		Polishing F	ilm			Process		
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time
1	Remove Epoxy	15	SiC	SC15	By hand	70 D	Dry	n/a	30-60s
				Clea	aning				
2	Rough Polishing	9	Diamond	D9	150g/pc	80 D	DI water	160-220rpm	50-60s
				Clea	aning				
4	Fine Polishing	1	Diamond	D1	150g/pc	80 D	DI water	160-220rpm	50-60s
	Cleaning								
5	Final Polishing	0.01	SiO2	ADS	150g/pc	70 D	DI water/ SOQ-12D	160-220rpm	40-60s
	Cleaning								



Note:

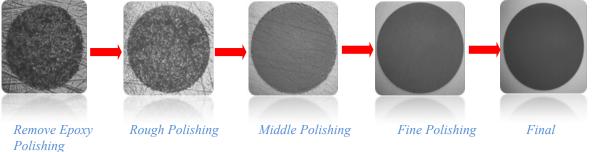
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





NANOMETER:

	C4		Polishing Filn	1		Process				
	Step	Micron	Mineral	Product ID	Pad	Liquid	Time			
1	Remove Epoxy	15/30	SiC/D	SC15/SC30/ D30	60 D	Dry	30-60			
	Cleaning									
2	Rough Polishing	9	Diamond	D9	60 D	DI water	2min			
	Cleaning									
3	Middle Polishing	3	Diamond	D3	60 D	DI water	1.5min			
	Cleaning									
4	Fine Polishing	1	Diamond	D1	60 D	DI water	1.5min			
5	Final Polishing	0.01	SiO2	ADS	50D	DI water/ SOQ-12D	1min			
				Cleaning						



Note:

In the grinding process, cleaning is very important.

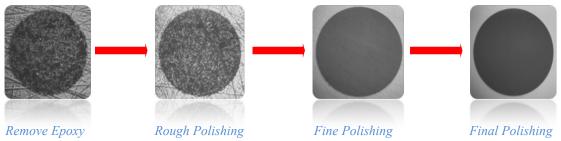
Effective cleaning can improve the yield and production efficiency of the product.





NANOMETER:

	C4 au		Polishing Filn	n		Process			
	Step	Micron	Mineral	Product ID	Pad	Liquid	Time		
1	Remove Epoxy	15/30	SiC/D	SC15/SC30 /D30	60 D	Dry	30-60s		
	Cleaning								
2	Rough Polishing	9	Diamond	D9	60 D	DI water	2min		
				Cleaning					
3	Fine Polishing	1	Diamond	D1	60 D	DI water	2min		
	Cleaning								
4	Final Polishing	0.01	SiO2	ADS	50D	DI water/ SOQ-12D	1min		
	Cleaning								



Note:

In the grinding process, cleaning is very important.

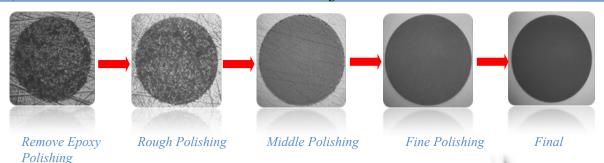
Effective cleaning can improve the yield and production efficiency of the product.





Seiko Instrument OFL-15(12UPC):

	C.		Polishing F	ilm			Process			
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time	
1	Remove Epoxy	15	SiC	SC15	By hand	n/a	Dry	n/a	30-50s	
	Cleaning									
2	Rough Polishing	9	Diamond	D9	1500g	60 D	DI water	160-220rpm	30-50s	
	Cleaning									
3	Middle Polishing	3	Diamond	D3	1800g	60 D	DI water	160-220rpm	30-50s	
	Cleaning									
4	Fine Polishing	1	Diamond	D1	1800g	60 D	DI water	160-220rpm	30-50s	
Cleaning										
5	Final Polishing	0.01	SiO2	ADS	1500g	50 D	DI water/ SOQ-12D	160-220rpm	30-40s	
				Cle	eaning					



Note:

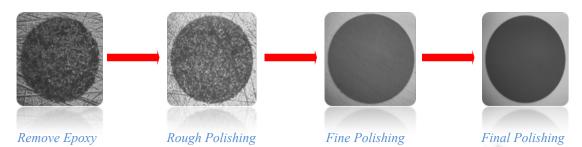
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





Seiko Instrument OFL-15(12UPC):

	C4		Polishing F	ilm			Process		
	Step	Micron	Mineral	Product ID	Pressure	Pad	Liquid	Speed	Time
1	Remove Epoxy	15/30	SiC/D	SC15/SC30 D30	By hand	n/a	Dry	n/a	40-60s
	Cleaning								
2	Rough Polishing	9	Diamond	D9	1800g	60 D	DI water	160-220rpm	40-60s
				Cle	eaning				
3	Fine Polishing	1	Diamond	D1	1800g	60 D	DI water	160-220rpm	40-60s
Cleaning									
4	Final Polishing	0.01	SiO2	ADS	1500g	50 D	DI water/ SOQ-12D	140-220rpm	30-40s
		•		Cle	eaning		-		



Note:

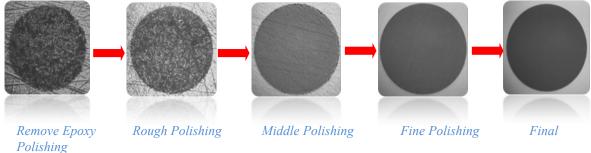
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





ULTRAPOL Polisher 1200:

	C4		Polishing F	ilm	Proc	ess				
	Step	Micron	Mineral	Product ID	Pad	Liquid				
1	Remove Epoxy	15/30	SiC/D	SC15/SC30/D30	Rubber pad	Dry				
	Cleaning									
2	Rough Polishing	9	Diamond	D9	Rubber pad	DI water				
	Cleaning									
3	Middle Polishing	3	Diamond	D3	Rubber pad	DI water				
	Cleaning									
4	Fine Polishing	1	Diamond	D1	Rubber pad	DI water				
				Cleaning						
5	Final Polishing	0.01	SiO2	ADS	Rubber pad	DI water/ SOQ-12D				
				Cleaning						



Note:

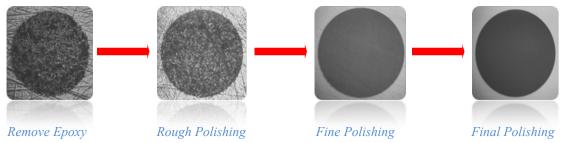
In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.





ULTRAPOL Polisher 1200:

	C4		Polishing F	ilm	Proc	ess			
L.	Step	Micron	Mineral	Product ID	Pad	Liquid			
1	Remove Epoxy	15/30	SiC	SC15/SC30	Rubber pad	Dry			
Ш			(Cleaning					
2	Rough Polishing	9	Diamond	D9	Rubber pad	DI water			
Ш			(Cleaning					
3	Fine Polishing	1	Diamond	D1	Rubber pad	DI water			
	Cleaning								
4	Final Polishing	0.01	SiO2	ADS	Rubber pad	DI water/ SOQ-12D			
	Cleaning								



Note:

In the grinding process, cleaning is very important. Effective cleaning can improve the yield and production efficiency of the product.



Suggested Process for Polishing FA



Seiko Giken SFP-550:

Step	Polishing Film	Polishing Liquid	ing Liquid Polishing Pad	
1 Remove Epoxy	SC30	Dry	Glass/Stainless Steel	0.5-1min
2 Angle Polishing	D30 /D15	DI water	Glass/Stainless Steel	3-5 min
3 Rough Polishing	D9	DI water	Glass/Stainless Steel	3-5 min
4 Middle Polishing	D3	DI water	Glass/Stainless Steel	2-3 min
5 Fine Polishing	D1	DI water	Glass/Stainless Steel	1-2min
6 Final Polishing	CO0.3/AO0.3	CO0.3/AO0.3 Slurry	Glass/Stainless Steel	1-2 min









Seiko Instrument OFL-12: (Speed: 120-150rpm)

Step	Polishing Film	Polishing Liquid	Polishing Pad	Pressure	Time	
1 Remove Epoxy	SC30	Dry	Glass/Stainless Steel	Point 2	0.5-1 min	
2 Angle Polishing	D30 /D15	DI water	Glass/Stainless Steel	Point 3	3-5 min	
3 Rough Polishing	D9	DI water	Glass/Stainless Steel	Point 3	3-5 min	
4 Middle Polishing	D3	DI water	Glass/Stainless Steel	Point 3	2-3 min	
5 Fine Polishing	D1	DI water	Glass/Stainless Steel	Point 3	1-2 min	
6 Final Polishing	CO0.3/AO0.3	CO0.3/AO0.3 Slurry	Glass/Stainless Steel	Point 3	1-2 min	



